

			Unit
			mA
			mA
			nA
			μC
			nF
			pF
			ns
			ns
			ns
			ns
		370	ns
t_f	Fall Time	T_J	ns
		70	ns

V_{GE} [V]

Figure 3. Typical Transfer characteristics IGBT-inverter

R_g [Ω]

Figure 4. Switching Energy vs Gate Resistor IGBT-inverter

MMG150HB060B6EN

Figure 14. Circuit Diagram